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CONFIRMATION NO. 4946

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APPLICANTS			·				
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** CONTINUING DATA **********************************							
** FOREIGN APPLICATIONS ************************************							
none, Of							
IF REQUIRED, FOREIGN FILING LICENSE GRANTED ** 12/05/2003							
Foreign Priority claimed 35 USC 119 (a-d) conditions met	yes Tho yes Tho Mot an	er /	STATE OR	SHEETS	TOTA	L INDEPENDENT	

COUNTRY

CA

DRAWING

CLAIMS

20

ADDRESS

Verified and Acknowledged

44182

MOSER, PATTERSON & SHERIDAN, LLP

APPLIED MATERIALS INC

595 SHREWSBURY AVE

SUITE 100

SHREWSBURY, NJ

07702

TITLE .

Process for etching polysilicon gates with good mask selectivity, critical dimension control, and cleanliness

CLAIMS

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	FEES: Authority has been given in Paper No to charge/credit DEPOSIT ACCOUNT No for following:	☐ All Fees
		1.16 Fees (Filing)
FILING FEE		1.17 Fees (Processing Ext. of time)
RECEIVED 750		☐ 1.18 Fees (Issue)
730		Other
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